## 1N4148WS-G

**Vishay Semiconductors** 



## Small Signal Fast Switching Diode



MARKING (example only)



Bar = cathode marking XY = type code

#### DESIGN SUPPORT TOOLS click logo to get started

22610



### FEATURES

- Silicon epitaxial planar diode
- · Fast switching diodes
- AEC-Q101 qualified available
- Base P/N-HG3 green, AEC-Q101 qualfied
- Base P/N-G3 green, commercial grade
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **MECHANICAL DATA**

Case: SOD-323

Weight: approx. 4 mg

#### Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE					
PART	ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMARKS	
1N4148WS-G	1N4148WS-G3-08 or 1N4148WS-G3-18	Single	АН	Tape and reel	
1N4148WS-HG	1N4148WS-HG3-08 or 1N4148WS-HG3-18	Single	An		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	75	M	
Repetitive peak reverse voltage		V <sub>RRM</sub>	100	v	
Average rectified current half wave rectification with resistive load <sup>(1)</sup>	$f \ge 50 Hz$	I <sub>F(AV)</sub>	150	mA	
Surge forward current	t < 1 s and $T_j$ = 25 °C	I <sub>FSM</sub>	350		
Power dissipation <sup>(1)</sup>		P <sub>tot</sub>	200	mW	

#### Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature.

<b>THERMAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air <sup>(1)</sup>		R <sub>thJA</sub>	650	K/W	
Junction temperature		Тj	150	°C	
Storage temperature range		T <sub>stg</sub>	-65 to +150	°C	
Operating temperature range		T <sub>op</sub>	-55 to +150	°C	

Note

<sup>(1)</sup> Valid provided that electrodes are kept at ambient temperature

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1

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 10 mA	VF			1	V
Forward voltage	I <sub>F</sub> = 100 mA	V <sub>F</sub>			1.2	V
	V <sub>R</sub> = 20 V	I <sub>R</sub>			25	nA
Leakage current	V <sub>R</sub> = 75 V	I <sub>R</sub>			5	μA
Leakage current	V <sub>R</sub> = 100 V	I <sub>R</sub>			100	
	V <sub>R</sub> = 20 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			50	
Diode capacitance	$V_F = V_R = 0 V$	CD			4	pF
Voltage rise when switching ON	Tested with 50 mA pulses, $t_p = 0.1 \ \mu s$ , rise time < 30 ns, $f_p = (5 \text{ to } 100) \text{ kHz}$	V <sub>fr</sub>			2.5	V
Reverse recovery time	$I_F = 10 \text{ mA}, i_R = 1 \text{ mA}, V_R = 6 \text{ V}, \\ R_L = 100 \ \Omega$	t <sub>rr</sub>			4	ns

#### TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

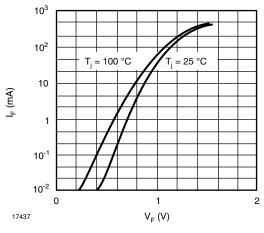


Fig. 1 - Forward Characteristics

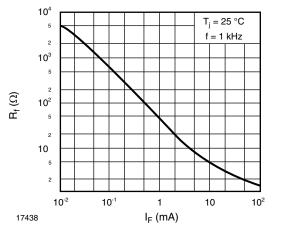


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

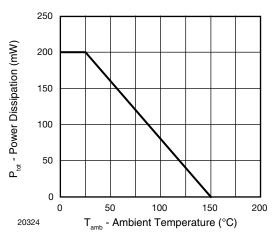


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

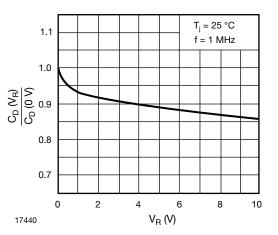


Fig. 4 - Relative Capacitance vs. Reverse Voltage

Rev. 1.4, 31-Jan-18

2

Document Number: 85413

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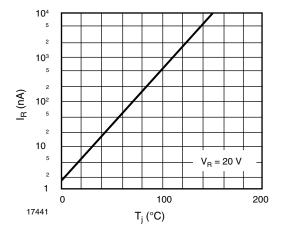


Fig. 5 - Leakage Current vs. Junction Temperature

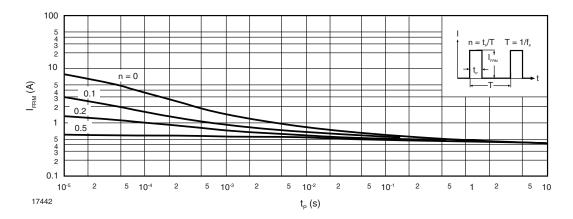
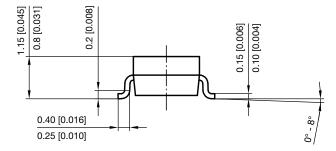


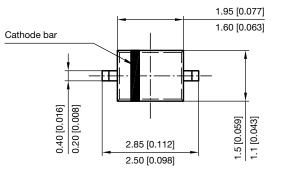
Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration

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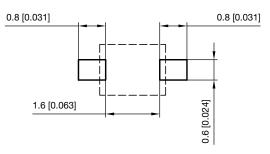


### PACKAGE DIMENSIONS in millimeters (inches): SOD-323





Footprint recommendation:

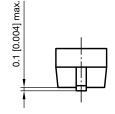


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 Rev. 1.4, 31-Jan-18
 4
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